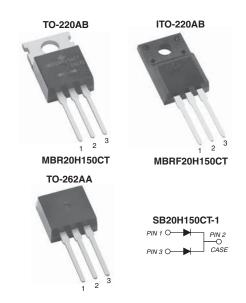


Vishay General Semiconductor

RoHS

Dual Common Cathode High Voltage Schottky Rectifier

Low Leakage Current 5.0 µA



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	150 V				
I _{FSM}	200 A				
V _F	0.75 V				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Dual Common Cathode				

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- · Low forward voltage drop
- High frequency operation
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



For use in high frequency inverters, freewheeling, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR20H150CT	MBRF20H150CT	SB20H150CT-1	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	150			V
Working peak reverse voltage		V_{RWM}	150			V
Maximum DC blocking voltage		V_{DC}	150			V
Maximum average forward rectified current	per device		20			А
	per diode	I _{F(AV)}	10			
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	f sine-wave	I _{FSM}	200			Α
Peak repetitive reverse current per diode at $t_p = 2 \mu s$, 1 kHz		I _{RRM}	1.0		Α	
Peak non-repetitive reverse surge energy per diode (8/20 µs waveform)		E _{RSM}	10		mJ	
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 1.5 \text{ A}$, $L = 10 \text{ mH}$		E _{AS}	11.25		mJ	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 65 to + 175		°C	
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V _{AC}	1500		V	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C	V _F ⁽¹⁾	0.90	V	
	I _F = 10 A	T _C = 125 °C		0.75		
	I _F = 20 A	T _C = 25 °C		0.99		
	I _F = 20 A	T _C = 125 °C		0.86		
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C	I _R ⁽¹⁾	5.0	μΑ	
		T _J = 125 °C		1.0	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.2	4.2	2.2	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H150CT-E3/45	2.06	45	50/tube	Tube		
ITO-220AB	MBRF20H150CT-E3/45	2.20	45	50/tube	Tube		
TO-262AA	SB20H150CT-1E3/45	1.58	45	50/tube	Tube		

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

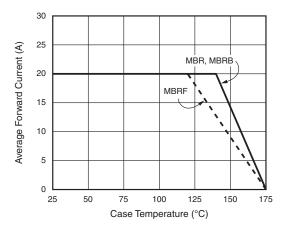


Fig. 1 - Forward Derating Curve (Total)

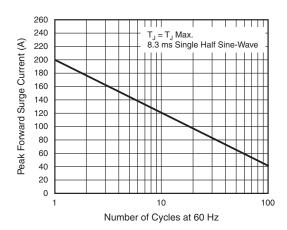


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

⁽¹⁾ AEC-Q101 qualified



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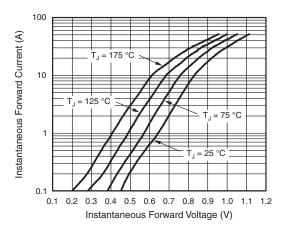


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

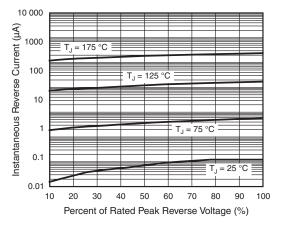


Fig. 4 - Typical Reverse Characteristics Per Diode

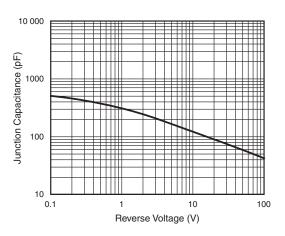


Fig. 5 - Typical Junction Capacitance Per Diode

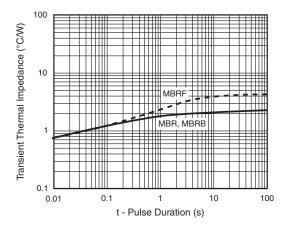
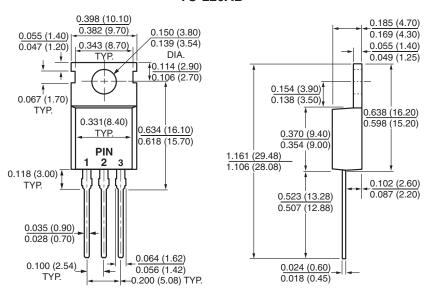


Fig. 6 - Typical Transient Thermal Impedance Per Diode

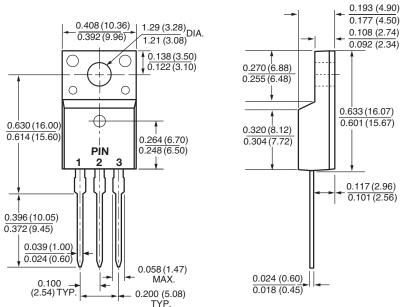
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



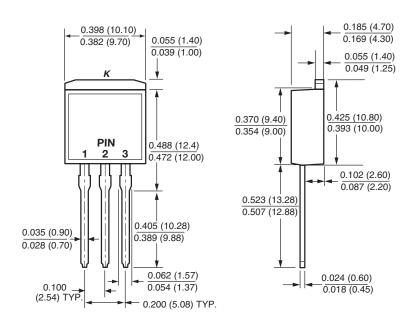
ITO-220AB





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TO-262AA





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